
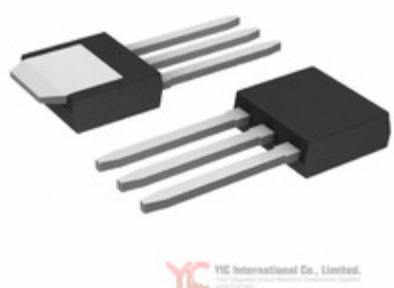
	<p>NTD12N10-1G</p>
	<p>Hersteller-Teilenummer: NTD12N10-1G</p> <p>Hersteller / Marke: AMI Semiconductor / ON Semiconductor</p> <p>Teil der Beschreibung: MOSFET N-CH 100V 12A IPAK</p> <p>Datenblätter:  NTD12N10-1G.pdf</p> <p>RoHs Status: Bleifrei / RoHS-konform</p> <p>Lagerzustand: New original, 2811 pcs Stock Available.</p> <p>Liefern von: Hong Kong</p> <p>Versandweg: DHL/Fedex/TNT/UPS/EMS</p>
	
<p>Image may be representation. See specs for product details.</p>	

Spezifikationen

Teilenummer	NTD12N10-1G
Hersteller	AMI Semiconductor / ON Semiconductor
Beschreibung	MOSFET N-CH 100V 12A IPAK
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs,
Teilstatus	2811 pcs Stock
Serie	-
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 175°C (TJ)
Befestigungsart	Through Hole
Verpackung / Gehäuse	TO-251-3 Short Leads, IPak, TO-251AA
Supplier Device-Gehäuse	I-Pak
Verlustleistung (max)	1.28W (Ta), 56.6W (Tc)
Typ FET	N-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	100V
Strom - Ununterbrochener Abfluss (Id) bei 25 ° C	12A (Ta)
Rds On (Max) @ Id, Vgs	165 mOhm @ 6A, 10V
VGS (th) (Max) @ Id	4V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	20nC @ 10V
Eingabekapazität (Ciss) (Max) @ Vds	550pF @ 25V
Verpackung	Tube

NTD12N10-1G ist neu im Original, Suche NTD12N10-1G Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie NTD12N10-1G AMI Semiconductor / ON Semiconductor mit Garantie und Vertrauen. Anfrage NTD12N10-1G: Info@Y-IC.com

Sie können auch interessiert sein:

 <p>NTD12N10G AMI Semiconductor / ON Semiconductor MOSFET N-CH 100V 12A DPAK</p>	 <p>NTD14N03 ON NTD14N03 ON</p>	 <p>NTD110N02RST4G AMI Semiconductor / ON Semiconductor MOSFET N-CH 24V 100A DPAK</p>	 <p>NTD12N10T4G AMI Semiconductor / ON Semiconductor MOSFET N-CH 100V 12A DPAK</p>
 <p>NTD12N10T4 AMI Semiconductor / ON Semiconductor MOSFET N-CH 100V 12A DPAK</p>	 <p>NTD110N02RG AMI Semiconductor / ON Semiconductor MOSFET N-CH 24V 12.5A DPAK</p>	 <p>NTD14N03G ON NTD14N03G ON</p>	 <p>NTD12N10-001 VB NTD12N10-001 VB</p>

heiße Teile

Mehr

- | | | | | |
|-----------------|------------------|------------------|-------------------|----------------|
| ⊗ NTD110N02 | ↔ NTD110N02R | ⇒ NTD110N02R-001 | D NTD110N02R-001G | ↔ NTD110N02RG |
| ⊣ NTD110N02RT4G | ⊗ NTD12N10-001 | D NTD12N10G | ⇒ NTD12N10T4 | ↔ NTD12N10T4G |
| ⊗ NTD14N03 | ⊣ NTD14N03G | ⊗ NTD14N03R | ↔ NTD14N03R-001 | ↔ NTD14N03R-1 |
| D NTD14N03R-1G | ⊗ NTD14N03RG | ⊣ NTD14N03RT4 | ⊗ NTD14N03RT4G | ↔ NTD14N03RTCG |
| ⇒ NTD14N03T4G | ↔ NTD15N06 | ⊗ NTD15N06L | ⊣ NTD15N06LG | ↔ NTD15N06LT4 |
| ↔ NTD15N06LT4G | ⇒ NTD15N06T4 | D NTD15N06T4G | ⊗ NTD15N06VLT4 | ⊣ NTD15N07 |
| ⊗ NTD15N10 | D NTD18N06-001 | ⇒ NTD18N06-1G | ↔ NTD18N06G | ↔ NTD18N06L |
| ⊣ NTD18N06L-1G | ⊗ NTD18N06LG | ↔ NTD18N06LT4G | ⇒ NTD18N06T4G | ↔ NTD20N03 |
| ⊗ NTD20N03G | ⊣ NTD20N03HL | ⊗ NTD20N03L27 | D NTD20N03L27G | ↔ NTD20N03L27T |
| ↔ NTD20N03L27T4 | ⊗ NTD20N03L27T4G | ⊣ NTD20N03RT4G | ⊗ NTD20N06 | ↔ NTD20N06-001 |

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HINZUFÜGEN: Einheit A5-B5 Nr.509, 5 / F Sing Win Fabrikgebäude, 15-17 Shing Yip St, Kwun Tong, Kowloon, HongKong.

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